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WS3A006120E Silicon Carbide Schottky Diode

Features

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- AC/DC converters

V _{RRM}	=	1200	V
I _F (T _C ≤135℃)	=	9.5	А
Qc	=	20	nC

Package





TO-252



Part Number	Package	Marking
WS3A006120E	TO-252	WS3A006120E

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V	$T_{C} = 25^{\circ}C$	
V _{RSM}	Surge Peak Reverse Voltage	1200	V	T _C = 25°C	
V _R	DC Blocking Voltage	1200	V	T _C = 25°C	
I _F	Forward Current	19 9.5 6	A	T _C ≤ 25°C T _C ≤ 135°C T _C ≤ 160°C	
I _{FSM}	Non-Repetitive Forward Surge Current	60	А	T_{C} = 25 $^{\circ}C$, t_{p} = 8.3ms, Half Sine Wave	
P _{tot}	Power Dissipation	136	W	$T_{C} = 25^{\circ}C$	Fig.3
Tc	Maximum Case Temperature	160	°C		
T_J, T_{STG}	Operating Junction and Storage Temperature	-55 to 175	°C		



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Valtage	1.55	1.8	V	$I_F = 6A, T_J = 25^{\circ}C$	Fig 1
۷F	Forward Voltage	2.2	2.5	V	$I_F = 6A, T_J = 175^{\circ}C$	Fig.1
	Devere Overset	2	20		$V_R = 1200V, T_J = 25^{\circ}C$	E a O
I _R	Reverse Current	10	200	μA	$V_R = 1200V, T_J = 175^{\circ}C$	Fig.2
		387			$V_{R} = 0V, T_{J} = 25^{\circ}C, f = 1MHz$	
С	Total Capacitance	28	/	pF	$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5
		22			$V_R = 800V, T_J = 25^{\circ}C, f = 1MHz$	
0					$V_{R} = 800V, I_{F} = 6A$	
Qc	Total Capacitive Charge	20	/	nC	di/dt = 200A/µs, T _J = 25°C	Fig.4

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
R _{θJC}	Thermal Resistance from Junction to Case	1.1	°CW	Fig.6
R _{0JA}	Thermal Resistance from Junction to Ambient	80	°C/W	
T _{sold}	T _{sold} Soldering Temperature		°C	

Typical Performance







Figure 2. Reverse Characteristics



Typical Performance



Figure 3. Power Derating



Figure 5. Total Capacitance vs. Reverse Voltage



Figure 4. Total Capacitive Charge vs. Reverse Voltage





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Package Dimensions

Package TO-252



PIN 1	0	
PIN 2	\bigcirc	

Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
А	6.3	6.5	6.7
В	5.2	5.3	5.4
С	1.15	1.25	1.35
D	5.7	5.9	6.1
E	0.65	0.7	0.75
F	2.1	2.3	2.5
G	2.2	2.3	2.4
Н	1.45	1.5	1.55
Ι	2.9	3.0	3.1
J	0.45	0.5	0.55
К	0.9	1	1.1

Simplified Diode Model

Equivalent IV Curve for Model



Mathematical Equation

$$V_F = V_t + I_F \times R_{diff}$$

$$V_{t} = -0.0011 \times T_{j} + 1 [V]$$

R_{diff} = 2.3×10⁻⁶×T_j² + 4.7×10⁻⁴×T_j + 0.086 [Ω]

Note:

$$\label{eq:time_time_time} \begin{split} Tj &= \text{Diode Junction Temperature In Degrees Celsius,} \\ \text{valid from 25°C to 175°C} \\ I_{\text{F}} &= \text{Forward Current} \\ \text{Less than 12A} \end{split}$$

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